Dual Matched General Purpose Transistor

NPN Matched Pair

These transistors are housed in an ultra-small SOT-363 package ideally suited for portable products. They are assembled to create a pair of devices highly matched in all parameters, eliminating the need for costly trimming. Applications are Current Mirrors; Differential, Sense and Balanced Amplifiers; Mixers; Detectors and Limiters.

Features

- Current Gain Matching to 10%
- Base-Emitter Voltage Matched to 2 mV
- Drop-In Replacement for Standard Device
- AEC-Q101 Qualified and PPAP Capable
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--------------------------------|------------------|-------|------|
| Collector - Emitter Voltage | V _{CEO} | 45 | V |
| Collector - Base Voltage | V _{CBO} | 50 | V |
| Emitter - Base Voltage | V _{EBO} | 6.0 | V |
| Collector Current - Continuous | I _C | 100 | mAdc |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------------------------|-------------|-------|
| Total Device Dissipation Per Device FR-5 Board (Note 1) T _A = 25°C | P _D | 380 250 | mW |
| Derate Above 25°C | | 3.0 | mW/°C |
| Thermal Resistance, Junction to Ambient | $R_{	hetaJA}$ | 328 | °C/W |
| Junction and Storage Temperature Range | T _J , T _{stg} | -55 to +150 | °C |

1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in

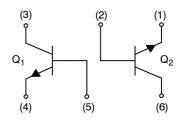


ON Semiconductor®

http://onsemi.com



SOT-363 CASE 419B STYLE 1



MARKING DIAGRAMS



2F = Device Code M = Date Code • = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-----------------|----------------------|-------------------------|
| NST45011MW6T1G | SOT-363 (Pb-Free) | 3,000 / Tape & Reel |
| NSVT45011MW6T3G | SOT-363 (Pb-Free) | 10,000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|--|---|-------------------|-----------------|-------------------|----------|
| OFF CHARACTERISTICS | | | | | |
| Collector – Emitter Breakdown Voltage, (I _C = 10 mA) | V _{(BR)CEO} | 45 | - | _ | V |
| Collector – Emitter Breakdown Voltage, (I _C = 10 μA, V _{EB} = 0) | V _{(BR)CES} | 50 | - | _ | V |
| Collector – Base Breakdown Voltage, (I _C = 10 μA) | V _{(BR)CBO} | 50 | - | _ | V |
| Emitter – Base Breakdown Voltage, (I _E = 1.0 μA) | V _{(BR)EBO} | 6.0 | _ | - | V |
| Collector Cutoff Current $(V_{CB} = 30 \text{ V})$ $(V_{CB} = 30 \text{ V}, T_A = 150 ^{\circ}\text{C})$ | I _{CBO} | - - | _ _ | 15 5.0 | nA μA |
| ON CHARACTERISTICS | | | • | | |
| DC Current Gain $ \begin{array}{l} (I_C = 10~\mu\text{A},~V_{CE} = 5.0~\text{V}) \\ (I_C = 2.0~\text{mA},~V_{CE} = 5.0~\text{V}) \\ (I_C = 2.0~\text{mA},~V_{CE} = 5.0~\text{V})~(\text{Note 2}) \end{array} $ | h _{FE} | 150 200 0.9 | - 300 1.0 | - 500 1.1 | - |
| Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$) ($I_C = 100 \text{ mA}, I_B = 5.0 \text{ mA}$) | V _{CE(sat)} | - - | _ _ | 250 600 | mV |
| Base – Emitter Saturation Voltage (I_C = 10 mA, I_B = 0.5 mA) (I_C = 100 mA, I_B = 5.0 mA) | V _{BE(sat)} | 700 850 | 750 890 | 800 950 | mV |
| Base – Emitter On Voltage ($I_C = 2.0$ mA, $V_{CE} = 5.0$ V) ($I_C = 10$ mA, $V_{CE} = 5.0$ V) ($I_C = 2.0$ mA, $V_{CE} = 5.0$ V) (Note 3) | V _{BE(0n)} V _{BE(1) -} V _{BE(2)} | 580 - - | 660 - 1.0 | 700 770 2.0 | mV |
| SMALL-SIGNAL CHARACTERISTICS | | | | | |
| Current - Gain - Bandwidth Product, (I _C = 10 mA, V _{CE} = 5 Vdc, f = 100 MHz) | f _T | 100 | _ | - | MHz |
| Output Capacitance, (V _{CB} = 10 V, f = 1.0 MHz) | C _{ob} | - | - | 4.5 | pF |
| Noise Figure, (I _C = 0.2 mA, V_{CE} = 5 Vdc, R_S = 2 k Ω , f = 1 kHz, BW = 200Hz) | NF | - | - | 10 | dB |

h_{FE(1)}/h_{FE(2)} is the ratio of one transistor compared to the other transistor within the same package. The smaller h_{FE} is used as numerator.
 V_{BE(1)} - V_{BE(2)} is the absolute difference of one transistor compared to the other transistor within the same package.

TYPICAL CHARACTERISTICS

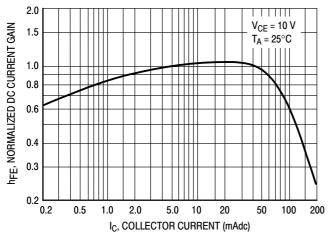


Figure 1. Normalized DC Current Gain

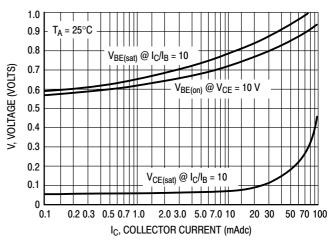


Figure 2. "Saturation" and "On" Voltages

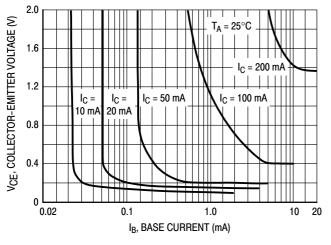


Figure 3. Collector Saturation Region

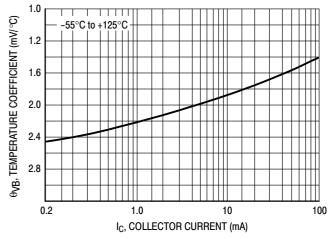


Figure 4. Base-Emitter Temperature Coefficient

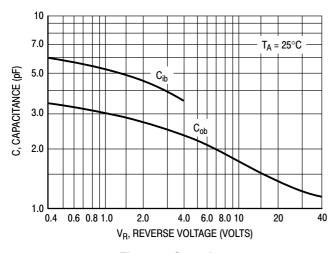


Figure 5. Capacitances

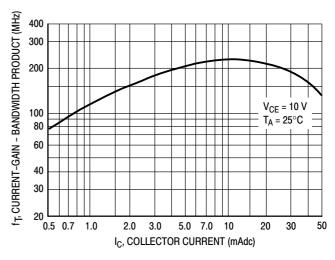


Figure 6. Current-Gain - Bandwidth Product

TYPICAL CHARACTERISTICS

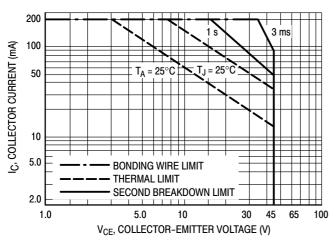


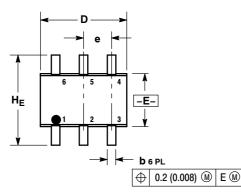
Figure 7. Active Region Safe Operating Area

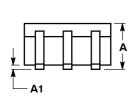
The safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

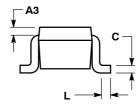
The data of Figure 7 is based upon $T_{J(pk)}$ = 150°C; T_{C} or T_{A} is variable depending upon conditions.

PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUF W







NOTES:

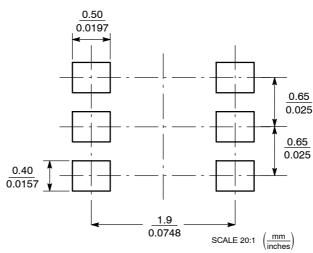
- DIMENSIONING AND TOLERANCING PER ANSI
- 2. CONTROLLING DIMENSION: INCH.
- 3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

| | MILLIMETERS | | | INCHES | | | |
|-----|-------------|------|------|-----------|-------|-------|--|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX | |
| Α | 0.80 | 0.95 | 1.10 | 0.031 | 0.037 | 0.043 | |
| A1 | 0.00 | 0.05 | 0.10 | 0.000 | 0.002 | 0.004 | |
| A3 | 0.20 REF | | | 0.008 REF | | | |
| b | 0.10 | 0.21 | 0.30 | 0.004 | 0.008 | 0.012 | |
| С | 0.10 | 0.14 | 0.25 | 0.004 | 0.005 | 0.010 | |
| D | 1.80 | 2.00 | 2.20 | 0.070 | 0.078 | 0.086 | |
| Е | 1.15 | 1.25 | 1.35 | 0.045 | 0.049 | 0.053 | |
| е | 0.65 BSC | | | 0.026 BSC | | | |
| L | 0.10 | 0.20 | 0.30 | 0.004 | 0.008 | 0.012 | |
| HE | 2.00 | 2.10 | 2.20 | 0.078 | 0.082 | 0.086 | |

STYLE 1:

PIN 1. EMITTER 2

- 2. BASE 2 3. COLLECTOR 1
- 4. EMITTER 1
- 5 BASE 1
- 6. COLLECTOR 2
- **SOLDERING FOOTPRINT***



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center

Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative